



## N-Channel Enhancement Mode Field Effect Transistor

### Product Summary

$V_{DS}$	60V
$I_D$	3A
$R_{DS(ON)}$ ( at $V_{GS}=10V$ )	85m
$R_{DS(ON)}$ ( at $V_{GS}=4.5V$ )	95m

### General Description

Trench Power LV MOSFET technology  
High Speed switching  
Halogen Free  
Moisture Sensitivity Level 1  
Epoxy Meets UL 94 V-0 Flammability Rating  
Halogen Free

### Applications

Power switching application  
PWM application

### Absolute Maximum Ratings ( $T_A=25$ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-source Voltage	$V_{DS}$	60	V	
Gate-source Voltage	$V_{GS}$	$\pm 20$	V	
Drain Current	$I_D$	$T_A=25$	3	A
		$T_A=100$	1.9	
Pulsed Drain Current <sup>A</sup>	$I_{DM}$	18	A	
Total Power Dissipation <sup>B</sup>	$P_D$	$T_A=25$	1.2	W
		$T_A=100$		



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## Electrical Characteristics ( $T_J=25$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>Static Parameter</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	60	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60V, V_{GS}=0V$	-	-	1	$\mu A$
		$V_{DS}=60V, V_{GS}=0V, T_J=150$	-	-	100	
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.9	1.35	2	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=3A$	-	62	85	m
		$V_{GS}=4.5V, I_D=3A$	-	70	95	
Diode Forward Voltage	$V_{SD}$	$I_S=3A, V_{GS}=0V$	-	0.85	1.2	V

Gate resistance

R





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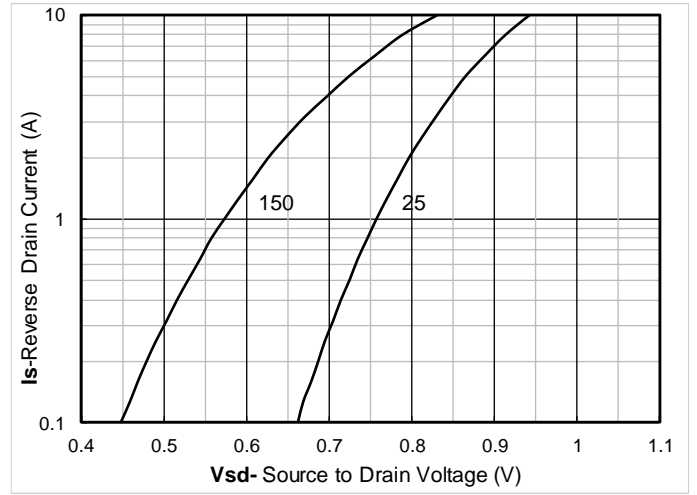
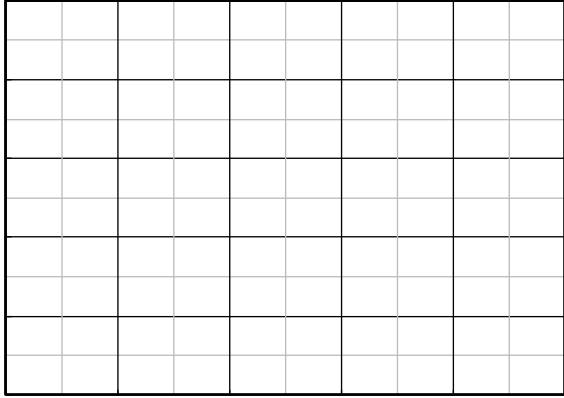


Figure 7. RDS(on)

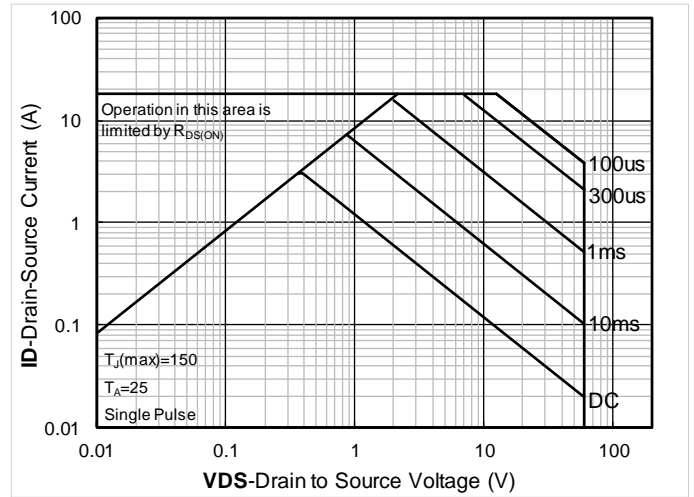


Figure 13. Maximum Transient Thermal Impedance

Figure 14. Safe Operation Area

## Test Circuits & Waveforms

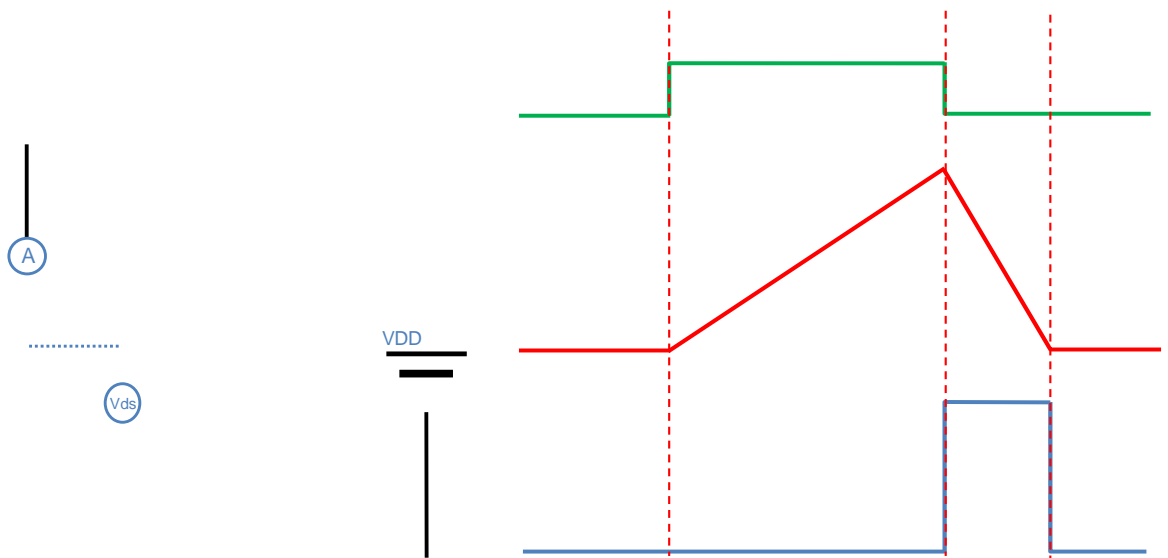


Figure A. Unclamped Inductive Switching (UIS) Test Circuit & Waveform

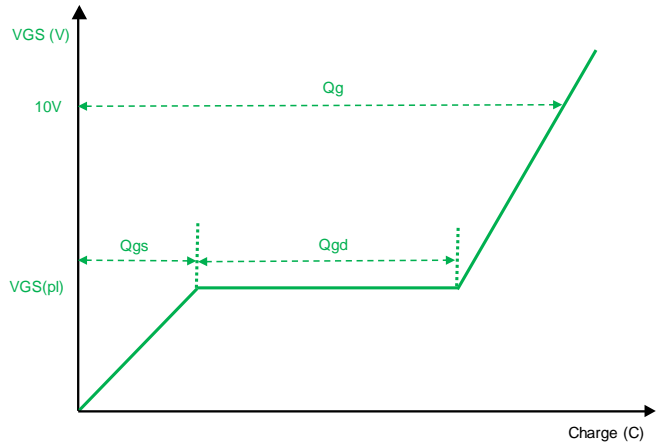
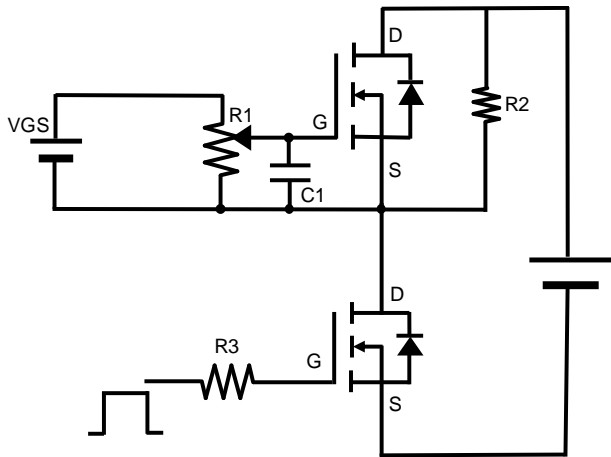


Figure B. Gate Charge Test Circuit & Waveform

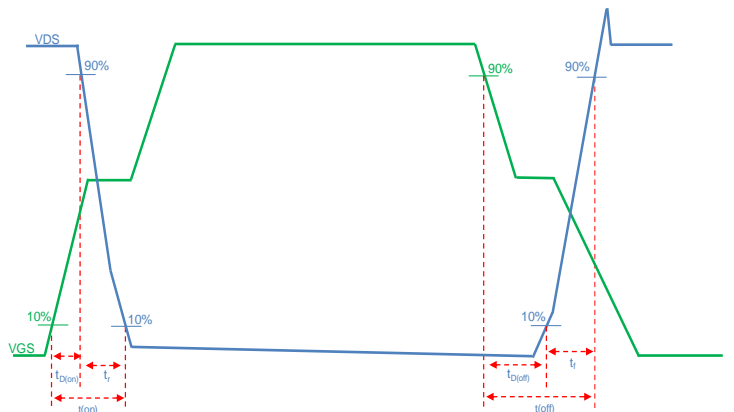
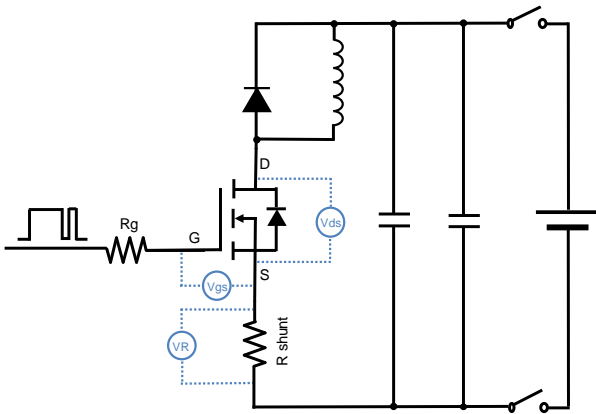


Figure C. Resistive Switching Test Circuit & Waveform

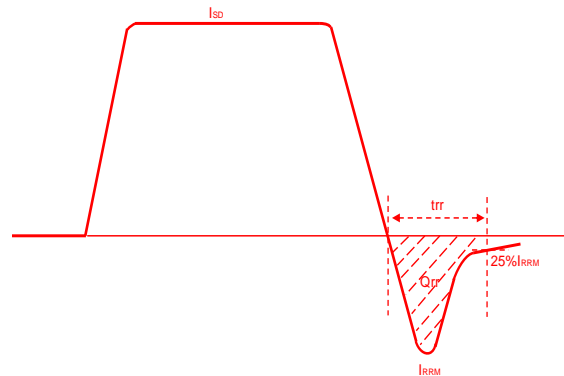
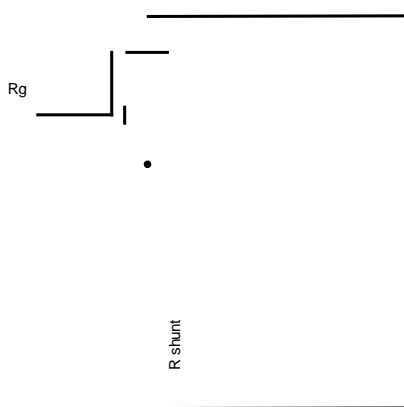
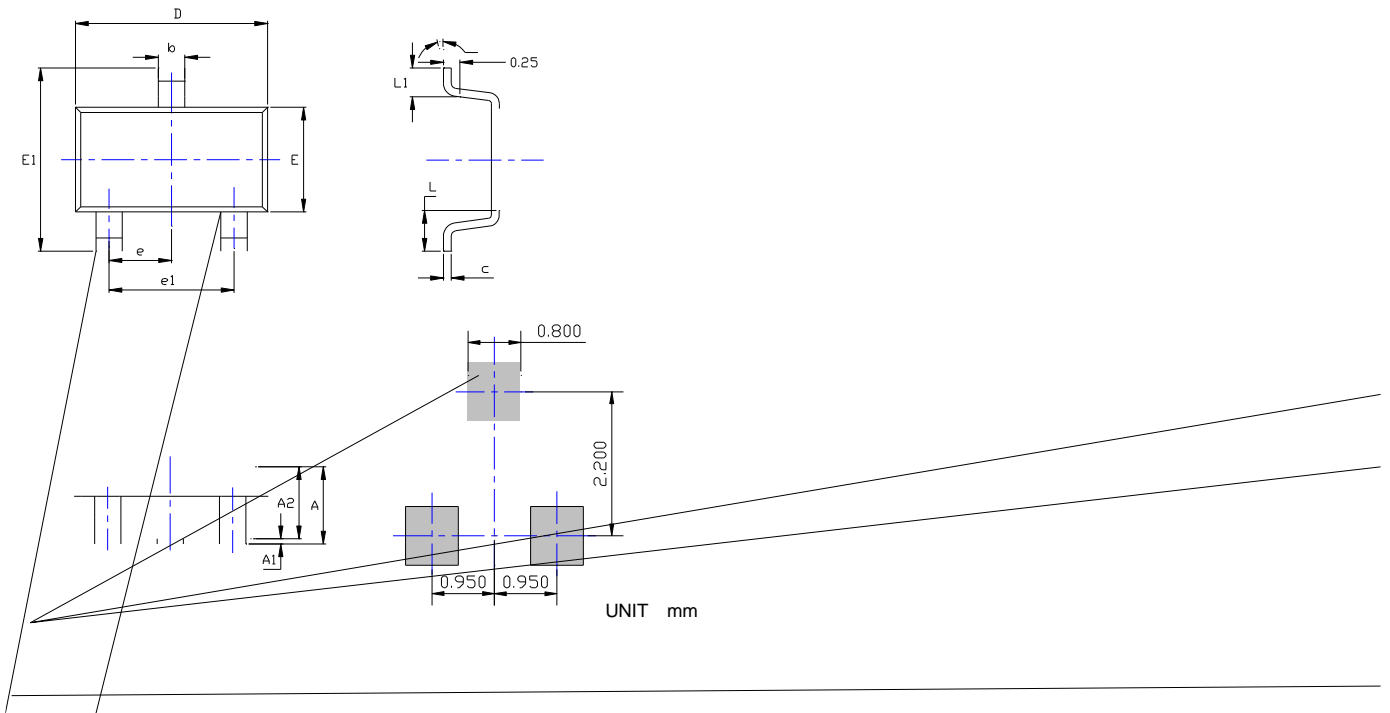


Figure D. Diode Recovery Test Circuit & Waveform



SOT-23-3L Package information





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